Elastic and optical properties of sillenites: First principle calculations

Husnu Koc, Selami Palaz, Sevket Simsek, Amirullah M. Mamedov & Ekmel Ozbay

To cite this article: Husnu Koc, Selami Palaz, Sevket Simsek, Amirullah M. Mamedov & Ekmel Ozbay (2020) Elastic and optical properties of sillenites: First principle calculations, Ferroelectrics, 557:1, 98-104

To link to this article: https://doi.org/10.1080/00150193.2020.1713354

Published online: 07 Apr 2020.

Submit your article to this journal

Article views: 17

View related articles

View Crossmark data
Elastic and optical properties of sillenites: First principle calculations

Husnu Koc\textsuperscript{a}, Selami Palaz\textsuperscript{b}, Sevket Simsek\textsuperscript{c}, Amirullah M. Mamedov\textsuperscript{d,e}, and Ekmel Ozbay\textsuperscript{d}

\textsuperscript{a}Department of Physics Faculty of Science and Letters, Siirt University, Siirt, Turkey; \textsuperscript{b}Department of Physics, Faculty of Science and Letters, Harran University, Sanliurfa, Turkey; \textsuperscript{c}Department of Material Science and Engineering, Faculty of Engineering, Hakkari University, Turkey; \textsuperscript{d}Nanotechnology Research Center, Bilkent University, Bilkent, Ankara, Turkey; \textsuperscript{e}International Scientific Center, Baku State University, Baku, Azerbaijan

\textbf{ABSTRACT}

In the present paper, we have investigated the electronic structure of some sillenites - Bi\textsubscript{12}MO\textsubscript{20} (M = Ti, Ge, and Si) compounds based on the density functional theory. The mechanical and optical properties of Bi\textsubscript{12}MO\textsubscript{20} have also been computed. The second-order elastic constants have been calculated, and the other related quantities have also been estimated in the present work. The band gap trend in Bi\textsubscript{12}MO\textsubscript{20} can be understood from the nature of their electronic structures. The obtained electronic band structure for all Bi\textsubscript{12}MO\textsubscript{20} compounds is semiconductor in nature. Similar to other oxides, there is a pronounced hybridization of electronic states between M-site cations and anions in Bi\textsubscript{12}MO\textsubscript{20}. Based on the obtained electronic structures, we further calculate the frequency-dependent dielectric function and other optical functions.

\textbf{ARTICLE HISTORY}

Received 14 July 2019
Accepted 24 December 2019

\textbf{KEYWORDS}

ab initio calculation; electronic structure; mechanical properties; optical properties

1. Introduction

Individual dodecabismuth metal (M\textsuperscript{4+} = Ti\textsuperscript{4+}, Ge\textsuperscript{4+}, Si\textsuperscript{4+}) oxides compounds (Bi\textsubscript{12}MO\textsubscript{20} - BMO) with a sillenite-type structure are formed as a result of interaction of bismuth oxide with oxides of elements that can be tetrahedrally coordinated by oxygen [1]. BMO crystals are isostructural to the metastable body-centered cubic phase Y-Bi\textsubscript{2}O\textsubscript{3} have strong dielectric properties and are characterized by a variety of unusual physical effects (piezoelectric, elastic, electro- and elasto-optical, optical activity and photorefractivity) and belong to the I\textsubscript{2}3 space group, with no center of inversion. In BMO crystals tetrahedral positions of M ions can be statistically occupied by isomorphic mixture of M\textsuperscript{4+} cations (n = 2–5) with strongly differing ionic radii, which leads to a wide class sillenites [1,2]. At the atomic level, the mechanisms of unusually wide isomorphism with respect to M-cations in BMO crystal were considered in some earlier investigations. It was shown that the bismuth-oxygen sublattice plays a decisive role in the existence of a wide class of isomorphic sillenite type compounds. Theoretical researches on BMO...
involve energy calculations, photocatalysis analysis of them, effect on pressure and comparative study of crystal structure structures of all three pure sillenites [1–5]. So far, the most properties of sillenites (structural, optical and electronic) have been studied experimentally [6–9]. First electronic structure results of the BMO have been discussed in [10,11] by using local pseudopotential and Xα methods [12]. On the next step, some theoretical calculations of electronic structure and optical properties of BMO were calculated by using FP-LAPW method [13,14]. Neither of the above sited works has discussed the elastic properties of sillenites. Therefore, the first objective of our paper is to accurately determine elastic properties of BMO sillenites, as a first and necessary step toward the future investigation of the mechanical properties in these materials. To our knowledge, the elastic constants, Young’s modulus, shear modulus, Poisson’s ratio, sound velocities, Debye temperature have not been reported in detail for BMO so far. Our other objective is to determine electronic states and optical properties of sillenites in a wide energy region up to 30 eV and gather all these theoretical data at one place. In this regard, we have conducted calculations of BMO crystals based on the DFT. Details of calculations are presented in Sections “Calculation details and structure optimization” and “Results and discussion”.

2. Calculation detail and structure optimization

The crystal structure of the BMO’s is body centered cubic (I23 space group) and the prototip crystal is a mineral sillenite [1, 15,16]. The two basic building blocks of crystal structure are usually considered to be the (BiO7) polyhedrons interconnected in a complex manner and the (MO4) tetrahedrons situated at the corners and the center of the conventional unit cell. The primitive cell of BMO contains 33 atoms, of which the nonequivalent Bi on Wyckoff position 24f, and M on position 2a [1, 15,16]. In all of our calculations that were performed using the ab-initio total-energy and molecular-dynamics program VASP (Vienna ab-initio simulation program) [17–20] that was developed within the density functional theory (DFT), [21] the exchange-correlation energy function is treated within the GGA (generalized gradient approximation) by the density functional of Perdew et al [22]. The potentials used for the GGA calculations take into account the 3p²3s²[Ne] valence electrons of each Si-, 3d¹⁰4s²4p²[Ar] valence electrons of each Ge-, 4d²4s²[Ar] valence electrons of each Ti-, 5d¹⁰6s²6p³[Xe] valence electrons of each Bi-, and 2s²2p⁴ valence electrons of each O-atoms. When including a plane-wave basis up to a kinetic-energy cutoff equal to 21.6 Ha for all BMO compounds, the properties investigated in this work are well converged. The Brillouin-zone integration was performed using special k points sampled within the Monkhorst-Pack scheme [23]. We found that a mesh of 5×5×5 k points for all three compounds was required to describe the structural, mechanical, and electronic properties. This k-point mesh guarantees a violation of charge neutrality less than 0.008e. Such a low value is a good indicator for an adequate convergence of the calculations. The elastic constants are calculated by the efficient stress-strain method [14] as implemented in the VASP code. The optical properties were obtained by complex dielectric function \( \varepsilon(\omega) = \varepsilon_1(\omega) + i\varepsilon_2(\omega) \) where the details explained in Refs [24–26]. We also calculated dependence of the pressure on the electronic and optical properties of BMO up to 25 GPa from the DFT.
3. Results and discussion

3.1. Structure optimization and elastic properties of Bi₁₂MO₂₀

The BMO compounds belong to the sillenite family with the I23 symmetry, and have one molecule with 33 atoms in unit cells. We have made the geometry optimization using the experimental atomic positions and lattice parameters [1, 15,16] in the first step of our calculation. The optimized values of the calculated lattice parameter values are in good agreement with the experimental values [1–11].

The calculated elastic constants and acoustic parameters of BMO compounds with the “strain-stress” relationship [27] for I23 symmetry are shown in Tables 1 and 2. Three independent elastic constants for cubic BMOs are calculated. The mechanical stability criteria for cubic BMOs are C₁₁ > 0, C₄₄ > 0, C₁₁ > |C₁₂|, (C₁₁+C₁₂)>0. The polycrystalline bulk modulus (B) and the shear modulus (G) are obtained from the Voigt-Reuss-Hill (VRH) approximation [28–30] using the calculated elastic constants. The isotropic shear modulus is G=(Gᵥ+Gᵣ)/2. Here, Voigt’s shear modulus is Gᵥ=(C₁₁−C₁₂+3C₄₄)/5 while Reuss’s shear modulus is Gᵣ=5(C₁₁+C₁₂)C₄₄/[4C₄₄+3(C₁₁−C₁₂)]. The bulk modulus for cubic crystals is B₉=Bᵥ=(C₁₁+C₂₁)/3 [31,32]. Poisson’s ratio is ν = 1/2[B-(2/3)G]/(B+(1/3)G). The value of the Poisson’s ratio is always 0.1 for covalent materials and 0.25 for ionic materials. Young’s modulus is E = 9GB/(G + 3B). The calculated Young’s modulus gives a measure of hardness [33–35]. The Zener anisotropy factor is A = 2C₁₁/(C₁₁−C₁₂) [36]. The Zener anisotropy factor is an indicator of the degree of anisotropy in the solid structure. If the B/G ratio is less (higher) than 1.75, a material is brittle (ductile) [36]. It is well known that the Debye temperature (θ₃D) is a basic parameter associated with many physical properties of materials. The θ₃D obtained using elastic constants at low temperatures (the vibration excitation at this temperature only originates from the acoustic vibrations) is the same as determined from the specific temperature measurements. In addition, sound velocities (vₚ, vₜ, vₘ) and the θ₃D’s (νᵥ= [1/3(2/v₃ + 1/v₃)]⁻¹/³, νᵣ= [(3B + 4G)/3ρ]¹/², νₚ= [G/ρ]¹/², and θ₃D= h/k[3n/4π(N A ρ/Μ)]¹/³) [36] of the compounds considered are also calculated, and the results are shown in Table 2. Unfortunately, there are no theoretical and experimental values for comparing the obtained values. The ionic character in atomic bonding from the obtained Poisson’s ratio (ν = 0.26 for all compounds) for the base case can be said to be dominant. The calculated isotropic shear and bulk moduli values for compounds are very close to each other. It can be said to be less compressible materials from the calculated isotropic shear (65.6 for Bi₁₂SiO₂₀, and 63.3 for Bi₁₂GeO₂₀) and bulk (120.8 for Bi₁₂SiO₂₀, 117.9 for Bi₁₂GeO₂₀) moduli for these compounds. The Young’s modulus (E) is a measure of the stiffness, and if the value of Young’s modulus is large, as a result the high modulus of these materials indicates their stiffness. The calculated Young’s modulus values for these compounds are 166.5 for Bi₁₂SiO₂₀, and

Table 1. The calculated elastic constants (in GPa), isotropic bulk modulus (B, in GPa), shear modulus (G, in GPa), Young’s modulus (E, in GPa), Poisson’s ratio and Zener anisotropy factor for Bi₁₂MO₂₀ (M = Si and Ge).

<table>
<thead>
<tr>
<th>Material</th>
<th>Reference</th>
<th>C₁₁</th>
<th>C₁₂</th>
<th>C₄₄</th>
<th>B</th>
<th>G</th>
<th>E</th>
<th>ν</th>
<th>B/G</th>
<th>A</th>
</tr>
</thead>
<tbody>
<tr>
<td>Bi₁₂SiO₂₀</td>
<td>Present</td>
<td>212.49</td>
<td>74.98</td>
<td>63.49</td>
<td>120.8</td>
<td>65.6</td>
<td>166.5</td>
<td>0.27</td>
<td>1.84</td>
<td>0.923</td>
</tr>
<tr>
<td>Bi₁₂GeO₂₀</td>
<td>Present</td>
<td>206.69</td>
<td>73.57</td>
<td>61.19</td>
<td>117.9</td>
<td>63.3</td>
<td>161.1</td>
<td>0.27</td>
<td>1.86</td>
<td>0.919</td>
</tr>
</tbody>
</table>
Young's modulus is defined as the ratio of stress and strain, and used to provide a measure of the stiffness of the solid. Here, the highest Young's modulus belongs to BMO compounds. The value of the Poisson’s ratio is indicative of the degree of directionality of the covalent bonds. The value of Poisson’s ratio is small ($\nu = 0.1$) for covalent materials, whereas for ionic materials a typical value is 0.25 [35].

As can be seen in Table 1, the ionic contribution to inter atomic bonding for these compounds is dominant ($\nu = 0.27$ for both compounds). The Zener anisotropy factor $A$ obtained as, $A = 2C_{44}/(C_{11} - C_{12})$. The Zener anisotropy factor is an indicator of the degree of anisotropy in the solid structure. For a completely isotropic material, the factor $A$ takes the value of 1. When the value is smaller or greater than unity, it is a measure of the degree of elastic anisotropy. The calculated Zener anisotropy factor 0.923 and 0.919 for Bi$_{12}$SiO$_{20}$ and Bi$_{12}$GeO$_{20}$, respectively (Table 1), therefore, demonstrates that these materials have very small elastic anisotropy. The Debye temperature and sound velocity calculated for Bi$_{12}$SiO$_{20}$ and Bi$_{12}$GeO$_{20}$ compounds are shown in Table 2. Usually, the Debye temperature is low for soft materials, but is high for rigid materials. Consequently, these compounds can be called nearly rigid materials.

### 3.2. Electronic structure and density of states

The band structures of BMO compounds along the high symmetry directions “$\Gamma \rightarrow H \rightarrow N \rightarrow P \rightarrow \Gamma \rightarrow N$” [$\Gamma = (0,0,0)$, $H = (1/2, -1/2, 1/2)$, $P = (1/3, 1/4, 1/4)$, $N = (0,0,1/2)$] calculated, and have been shown in Figure 1. The calculations show that the valance band maximum and conduction band minimum for Bi$_{12}$SiO$_{20}$, Bi$_{12}$GeO$_{20}$ and Bi$_{12}$TiO$_{20}$ compounds are between $\Gamma$ and $H$ high symmetry points of the first Brillouin zone ($E_g = 2.42$ eV, 2.46 eV, and 2.40 eV, respectively) and they are in good agreement with the experimental values [7, 9–13]. Therefore, these compounds are piezoelectrics with an indirect band gap. For all calculated compounds we observed the next electronic states: 132 for Bi$_{12}$SiO$_{20}$, 157 for Bi$_{12}$GeO$_{20}$ and 152 for Bi$_{12}$TiO$_{20}$ in the energy region between (-30.0 and 0) eV. For Bi$_{12}$SiO$_{20}$ compound, the lowest valance bands, valance bands between -(30 – 20) eV and -(18 – 12) eV, and uppermost occupied valance

### Table 2. The calculated sound velocities ($v_t$, $v_l$, $v_m$) and the Debye temperatures for Bi$_{12}$MO$_{20}$ (M = Si and Ge).

<table>
<thead>
<tr>
<th>Material</th>
<th>Reference</th>
<th>$v_t$ (m/s)</th>
<th>$v_l$ (m/s)</th>
<th>$v_m$ (m/s)</th>
<th>$\theta_D$ (K)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Bi$<em>{12}$SiO$</em>{20}$</td>
<td>Present</td>
<td>2737</td>
<td>4877</td>
<td>3046</td>
<td>357</td>
</tr>
<tr>
<td>Bi$<em>{12}$GeO$</em>{20}$</td>
<td>Present</td>
<td>2690</td>
<td>4808</td>
<td>2994</td>
<td>349</td>
</tr>
</tbody>
</table>

![Figure 1. Energy band structure for a) Bi$_{12}$SiO$_{20}$, b) Bi$_{12}$GeO$_{20}$, and c) Bi$_{12}$TiO$_{20}$.](image)
bands are formed by Bi 6p states, the hybridization of O 2s – Bi 6p states (the Bi 6p states is dominant) and Si 2p-O 2s states (the O 2s states is dominant), respectively. For Bi$_{12}$GeO$_{20}$ compound, the lowest valance bands, valance bands between \((-30\text{--}10)\) eV, and uppermost occupied valance bands are formed by Bi 6p states, the hybridization of O 2s-Bi 6p states (the Bi 6p states is dominant). For the Bi$_{12}$TiO$_{20}$ compound, the lowest valance bands, valance bands between \((-40 \text{--} 15)\) eV, and uppermost occupied valance bands are formed by Ti 6s states, Ti 6p states, Bi 6p states and the hybridization of Bi 6p-O 2s states (the Bi 6p states is dominant). The highest valence bands for all investigated compounds are formed by O 2p states and hybridization of O 2p-M and (Si, Ge, and Ti) states (the O 2p states is dominant). The lowest unoccupied conduction bands above the Fermi energy for the three compounds are formed by the hybridization of p and d states, but d states is dominant. The pressure coefficient of Eg for investigated BMO appr. is 2 meV/kbar.

### 3.3. Optical properties

We have first calculated the real and imaginary part of $\varepsilon(\omega)=\varepsilon_1(\omega)-i\varepsilon_2(\omega)$ complex dielectric function using the Kramers-Kroning relations. The other optical functions such as energy-loss function, have been calculated with the help of the real and imaginary part of dielectric function for these compounds. The energy values of $\varepsilon_1$ that decreasing $(d\varepsilon_1)/(dE < 0)$ and increasing $(d\varepsilon_1)/(dE > 0)$ are zero are 6.66 eV (9.84 eV), 10.54 eV (10.61 eV) and 13.71 eV (19.91 eV) for Bi$_{12}$SiO$_{20}$ compound, 6.69 eV (9.88 eV), 10.28 eV (10.76 eV) and 13.63 eV (19.85 eV) for Bi$_{12}$GeO$_{20}$ compound, and 6.72 eV (10.72 eV), and 13.55 eV (20.16 eV) for Bi$_{12}$TiO$_{20}$ compound. These values that the $\varepsilon_1$ are zero are points reduced of the reflections, and show that the polarization disappears. The maximum of main peak values of $\varepsilon_2$ are 4.73 eV, 6.28 eV, 10.45 eV, 13.71 eV, 27.10 eV, 27.58 eV and 29.32 eV for Bi$_{12}$SiO$_{20}$ compound, 4.86 eV, 6.21 eV,10.20 eV, 13.35 eV, 27.1 27.66 eV, and 29.34 eV for Bi$_{12}$GeO$_{20}$ compound, and 4.84 eV, 6.25 eV, 10.14 eV, 12.03 eV, 13.68 eV,25.47 eV 26.60 eV and 29.40 eV for Bi$_{12}$TiO$_{20}$ compound. These values show how much the electromagnetic wave polarizes the system, and corresponds to the electronic transitions from the valance band to the conduction band. The pressure dependence on optical spectra only shifted maximum of main peaks of $\varepsilon_2$ to higher energy region but don’t change the structure of optical spectra in this region (2–30 eV). This energy region corresponds to the region beginning of the transition between the bands. The 2.0–15.0 eV energy region for these compounds is the region where the transitions between the bands are very intense. The energy region above 15 eV also corresponds to the collective vibration of valance electrons. This energy region defined as plasma oscillations is described by the energy loss function. The values of valence electrons plasma oscillation energy for Bi$_{12}$SiO$_{20}$, Bi$_{12}$GeO$_{20}$, and Bi$_{12}$TiO$_{20}$ compounds are 20.45 eV, 20.41 eV, and 19.60 eV, respectively.

### 4. Conclusions

We have performed the structural, mechanical, electronic, and optical properties of the BMO compounds using density functional theory within the GGA approximation. The
lattice parameters obtained as a result of geometric optimization are in good agreement with the experimental values. Because the calculated shear and bulk modules obtained by using the calculated elastic constants are very close to each other, Bi$_{12}$SiO$_{20}$ and Bi$_{12}$GeO$_{20}$ compounds are less compressible materials. Since the calculated Young’s modulus of the Bi$_{12}$SiO$_{20}$ compound is larger than the Bi$_{12}$GeO$_{20}$ compound, it can be said that the Bi$_{12}$SiO$_{20}$ compound is harder than the Bi$_{12}$GeO$_{20}$ compound. In both compounds, ionic character is dominant and these compounds have small elastic anisotropy. In the calculation of the calculated electronic band structure, BMO compounds are found as indirect band structured semiconductors in nature. The optical constants such as real and imaginary part of dielectric function, energy-loss function for these compounds were calculated.

References

[2] H. S. Horowitz et al., Solution synthesis and characterization of sillenite phases, Bi$_{24}$M$_2$O$_{40}$ (M = Si, Ge, V, As, P), Solid State Lonics. 32 (33), 678 (1989). DOI: 10.1016/0167-2738(89)90344-5.